PCN Number:			2	20130828000						PCN Date:			08/29/2013			
Titl	e:	INA271-HT	Dat	a S	She	et										
Customer Contact:			PC	PCN Manager			Phon	e: +1(214)480-603				Dept:	Qua	ality Services		
Proposed 1 st Ship Da			ite	te: 11/29/2013			13	Estimated Sample Availability:				Date provided upon request				
Cha	ange	Туре:														
☐ Assembly Site					Assembly Process						Α	Assembly Materials				
Design				X	Electrical Specification				M	Mechanical Specification						
☐ Test Site					Packing/Shipping/Labeling						Т	Test Process				
☐ Wafer Bump Site					Wafer Bump Material						W	Wafer Bump Process				
☐ Wafer Fab Site					☐ Wafer Fab Materials ☐					Wafer Fab Process						
	PCN Details															
Des	Description of Change:															

Description of Change:

The product datasheet(s) is being updated to update IQ high at 210C to 1.6mA

The following change history provides further details. These changes may be reviewed at the datasheet links provided.

From (page 5):



INA271-HT

www.ti.com

SBOS521C - SEPTEMBER 2010 - REVISED APRIL 2012

ELECTRICAL CHARACTERISTICS (continued)

At $T_A = +25$ °C, $V_S = +5$ V, $V_{CM} = +12$ V, $V_{SENSE} = 100$ mV, and PRE OUT connected to BUF IN, unless otherwise noted.

			T _A =	-55°C to	125°C	T _A = -	55°C to	175°C		T _A = 210	°C	
PARAMETER		CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
NOISE < RTI ⁽⁷⁾												
Voltage Noise Density	en			40						40		nV/√ Hz
POWER SUPPLY												
Operating Range	٧s		2.7		18				2.7		18	v
Quiescent Current	Ιq	VOUT = 2V V _{SENSE} = 0mV		740 350	1200 950					1160 895	1300 1300	μА
TEMPERATURE RANGE												
Specified Temperature Range			-55		125				-55		210	°C
Operating Temperature Range			-55		125				-55		210	°C

To (page 5):



INA271-HT

www.ti.com

SBOS521D - SEPTEMBER 2010-REVISED AUGUST 2013

ELECTRICAL CHARACTERISTICS (continued)

At T_A = +25°C, V_S = +5V, V_{CM} = +12V, V_{SENSE} = 100mV, and PRE OUT connected to BUF IN, unless otherwise noted.

			T _A =	–55°C to	125°C	T _A = -	55°C to	175°C		T _A = 210°	°C	
PARAMETER		CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
NOISE < RTI ⁽⁷⁾												
Voltage Noise Density	e _n			40						40		nV/√ Hz
POWER SUPPLY												
Operating Range	Vs		2.7		18				2.7		18	V
Quiescent Current	I۵	VOUT = 2V V _{SENSE} = 0mV		740 350	1200 950					1160 895	1600 1600	μА
TEMPERATURE RANG	BE .											
Specified Temperature Range			-55		125				-55		210	°C
Operating Temperature	Range		-55		125				-55		210	°C

The datasheet number will be changing.

Device Family	Change From:	Change To:
INA 271-HT	SBOS521C	SBOS521D

The updated datasheet(s) can be accessed by the following link(s): $\frac{http://www.ti.com/product/ina271-ht}{}$

Reason for Change:

To more accurately reflect device characteristics.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

Electrical specification performance changes as indicated above.

Changes to product identification resulting from this PCN:

None

Product Affected:

INA271SHKJ	INA271SHKQ	INA271SKGD1	

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

Texas Instruments, Inc.